

EL2041D Die*Wideband, Fast Settling, Unity Gain Stable, Operational Amplifiers*

T-79-07-10

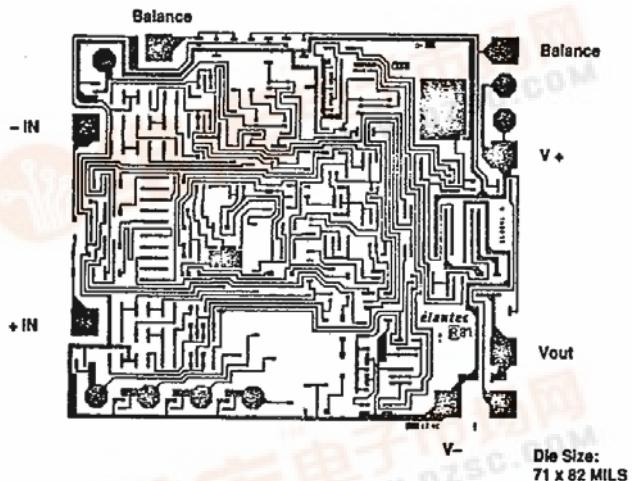
Absolute Maximum Ratings (TA = 25°C)

VS	Voltage between V+ and V-	35V
ΔVIN	Differential Input Voltage	6V
IOP	Output Current, Peak	50 mA
IOC	Output Current, Continuous	25 mA
TJ	Maximum Junction Temperature	175°C

Important Note:

For AC electrical characteristics, refer to the typical electrical table and performance curves in the package data sheet. These characteristics are guaranteed but not tested in die form. Unless otherwise noted, all tests are pulsed tests, therefore $T_J = T_C = T_A$.

Test Level	Test Procedure
I	100% production tested in wafer form. See remarks under Electrical Testing in the General Die section.

**DC Electrical Characteristics** VS = ±15V, RL = 1 kΩ, TA = 25°C

Parameter	Description	Min	Typ	Max	Test Level	Units
VOS	Offset Voltage		0.5	2	I	mV
IB	Bias Current		5	15	I	μA
IOS	Offset Current		1	4	I	μA
VCM	Common Mode Range	±8			I	V
AVOL	Large Signal Voltage Gain (Note 1)	7k	10k		I	V/V
CMRR	Common-Mode Rejection Ratio (Note 2)	70	80		I	dB
VO	Output Voltage Swing	±11			I	V
IO	Output Current (Note 4)	±25	±50		I	mA
IS	Supply Current		13	17	I	mA
PSRR	Power Supply Rejection Ratio (Note 3)	70	80		I	dB

Note 1: VO = ±10V.

Note 2: Two tests are performed. VCM = 0V to +8V and VCM = 0V to -8V.

Note 3: Two tests are performed. V+ = +15V, and V- is changed from -7V to -15V. V- = -15V, and V+ is changed from +7V to +15V.

Note 4: RL = 200Ω.